

Lab. 13

DESIGN AND CHARACTERIZATION OF FULL-DIFFERENTIAL OPA

1. Design of full-differential OPA

- Determine the sizes of the MOSFETs and fill in the blank of Table I.
 - The area and perimeter of MOSFET are given by $W \cdot 3u$ and $W + 6u$, respectively.

Target specifications

Parameter	Unit	Value	Remarks
GBP	Hz	40M	$CL = 1.0\text{pF}$
A_d	dB	100	@ 10Hz
Phase Margin	degree	60	
Slew Rate	V/us	10	$CL = 1.0\text{pF}$
Bias Current	A	200u	
Reference Current	A	10u	$I_{SS} = 20\mu\text{A}$

Table I

Folded-cascode differential amplifier

MOSFET	L(m)	W(m)	M	AD, AS(m ²)	PD, PS(m)	W/L
M1, M2						
M3, M4, M7-M10	2u	10u	3	30p	16u	15
M5, M6, M11-M13	2u	10u	1	30p	16u	5

The size of M1 and M2 can be estimated from the GBP and CL.

CMFB

MOSFET	L(m)	W(m)	M	AD, AS(m ²)	PD, PS(m)	W/L
M1-M4	2u	16u	8	48p	22u	64
M5-M12						
M13-M16	2u	10u	1	30p	16u	5

Remember that the CMFB circuit is a replica of the current source load of the amplifier.

Table II

BIAS

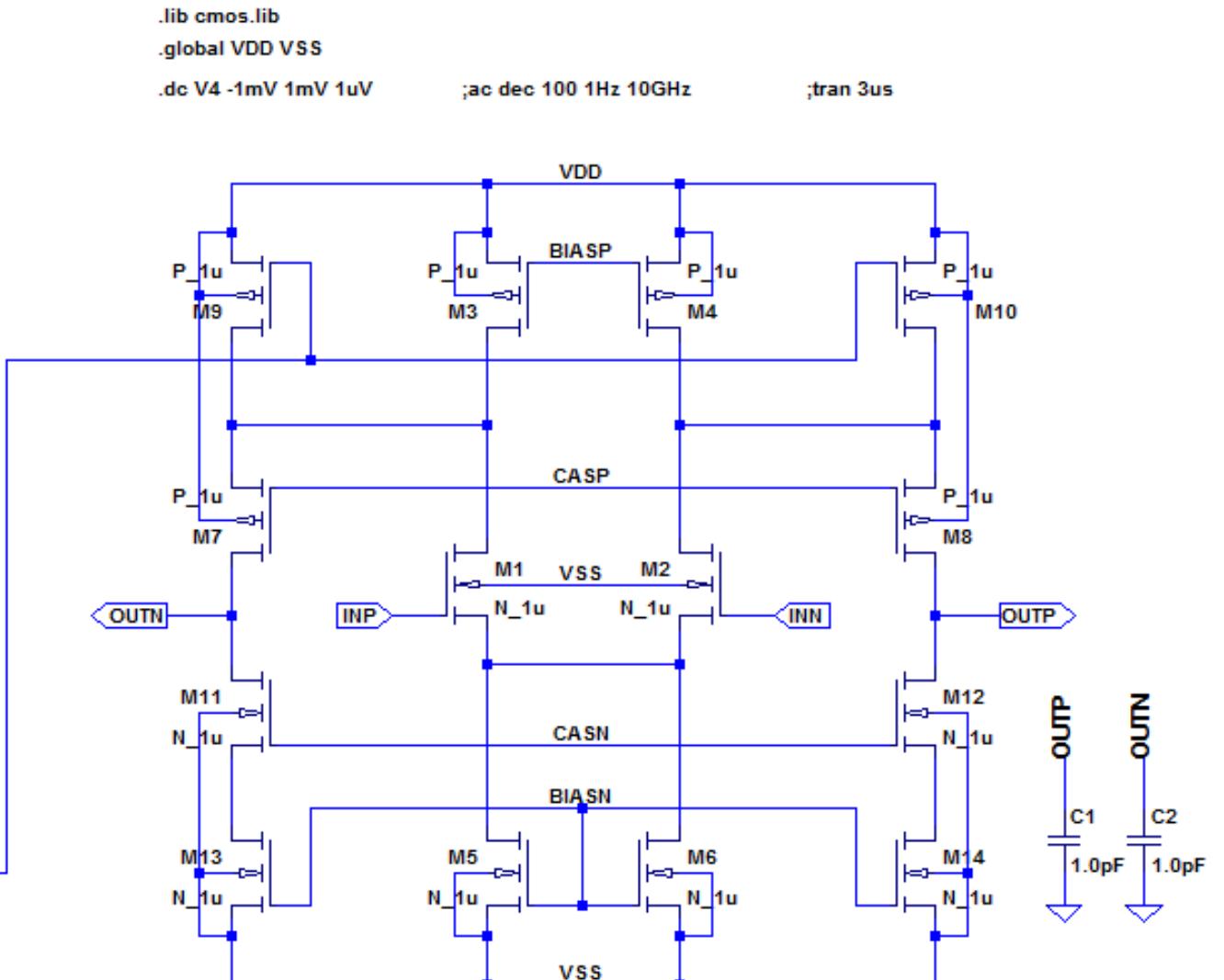
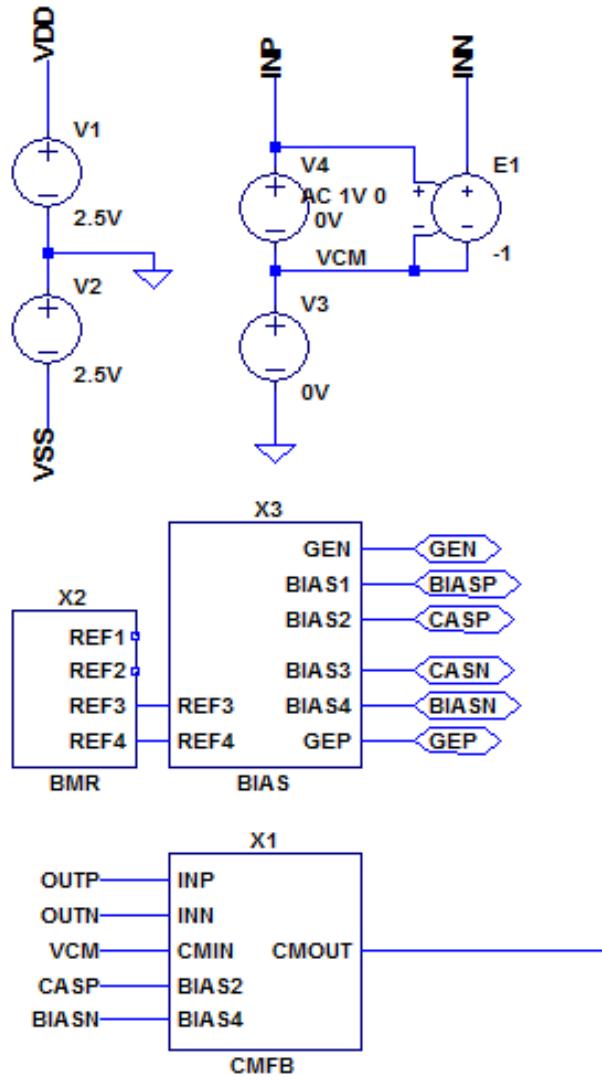
MOSFET	L(m)	W(m)	M	AD, AS(m ²)	PD, PS(m)	W/L
p-ch MOSFET	2u	10u	3	30p	16u	15
n-ch MOSFET	2u	10u	1	30p	16u	5

$$\Delta_{OV_p-ch} = \sqrt{\frac{2I_{DS}}{\beta_p}} = \sqrt{\frac{2 \cdot 10\mu A}{33\mu A/V^2 \cdot 15}} = 0.201V \quad \Delta_{OV_n-ch} = \sqrt{\frac{2I_{DS}}{\beta_n}} = \sqrt{\frac{2 \cdot 10\mu A}{98\mu A/V^2 \cdot 5}} = 0.202V$$

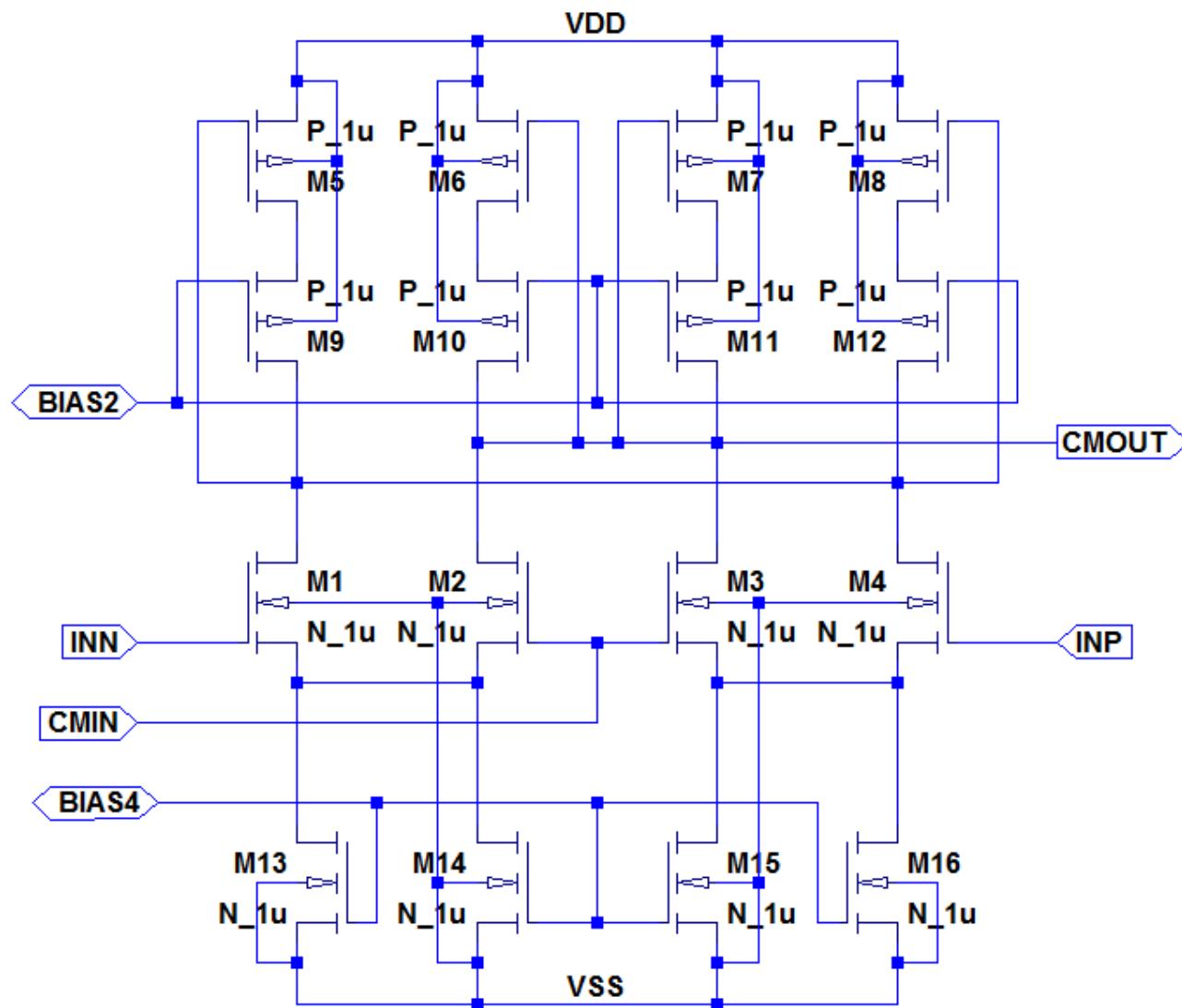
BMR

MOSFET	L(m)	W(m)	M	AD, AS(m ²)	PD, PS(m)	W/L
M1, M3, M4, M9, M10	2u	10u	1	30p	16u	5
M2	2u	10u	4	30p	16u	20
M5-M8	2u	10u	3	30p	16u	15
M11-M29	5u	5u	1	115p	11u	1

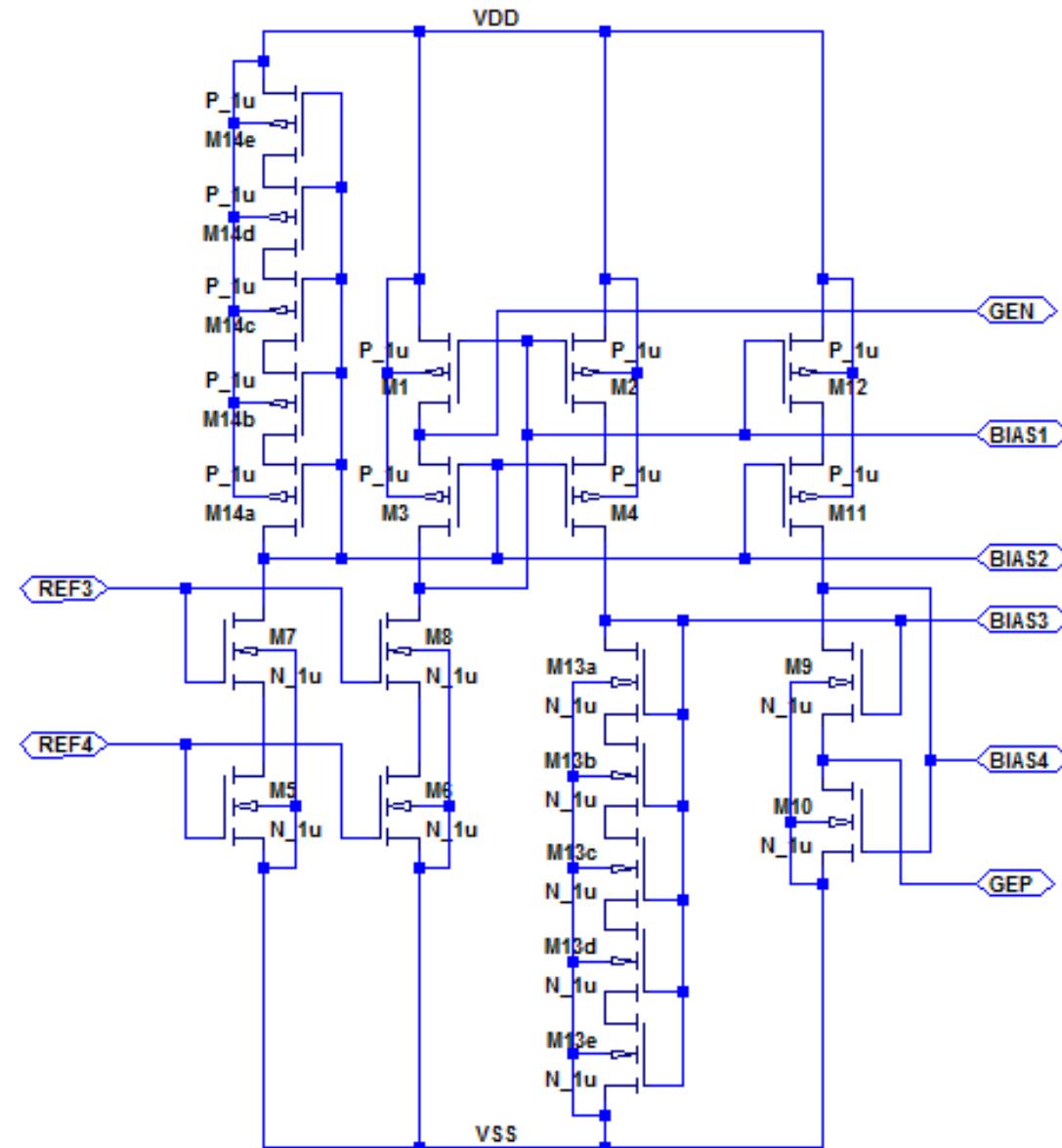
Folded cascode differential amplifier



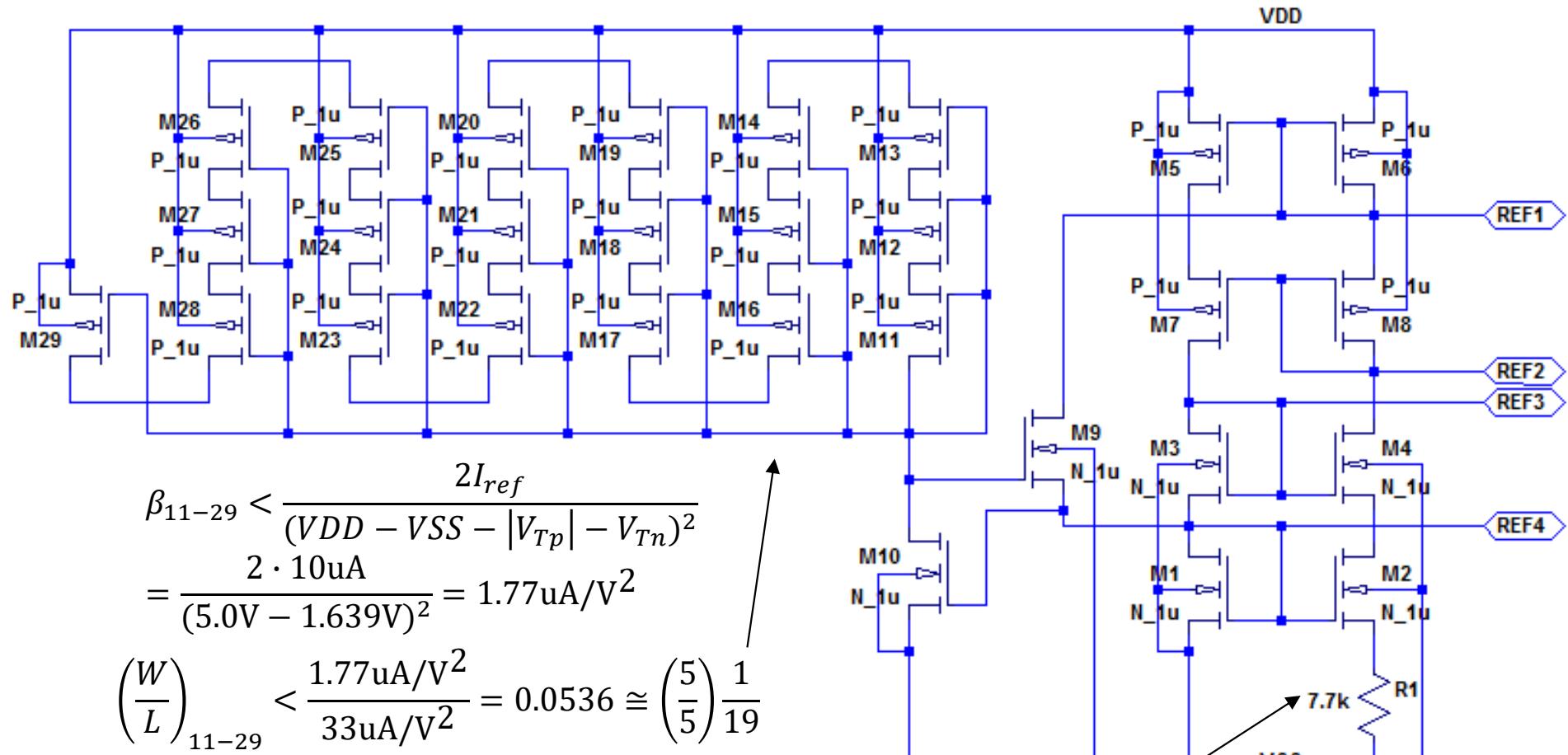
CMFB



Bias



BMR



$$R1 = \sqrt{\frac{2}{\beta_1 I_{ref}}} \left(1 - \frac{1}{\sqrt{K}}\right) = \sqrt{\frac{2}{98\mu A/V^2 \cdot 5 \cdot 10\mu A}} \left(1 - \frac{1}{\sqrt{4}}\right) = 10.1k\Omega \quad (\text{Adjusted})$$

2. Characterization

- Carry out the DC, AC, and TRAN analysis of the full-differential OPA and attach the simulation results to your report.
 - DC characteristic of $V(\text{inp})$, $V(\text{inn})$, $V(\text{outp})$, $V(\text{outn})$, $V(\text{cmfb})$, $I_d(M1)$, $I_d(M2)$, and $I(V1)$
 - Check the offset voltage. The systematic offset should be removed by the CMFB.
 - AC characteristic of $V(\text{outp})$ and $V(\text{outn})$
 - The step response (TRAN characteristics) of $V(\text{inp})$, $V(\text{inn})$, $V(\text{outp})$, and $V(\text{outn})$
- Fill out the blank in Table III by using your simulation results.

Table III

- The specification estimated by the simulation.

Parameter	Unit	Value	Remarks
GBP	Hz		CL = 1.0pF
A_d	dB		@ 10Hz
Phase Margin	degree		
Slew Rate	V/us		CL = 1.0pF
Total Bias Current	A		
Reference Current	A		$I_{SS}/2$